Product data sheet

1. General description

WMS30N1200SK is a high performance super logic level N-channel MOSFET in SOT23 package, which utilizes advanced Trench MOSFET technology to provide low $R_{\mathrm{DS(on)}}$ and gate charge. It is designed and qualified in a wide range of industrial and consumer applications.



2. Features and benefits

- · High ESD sensitivity devices
- Advance High Cell Density Trench Technology
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Switching Losses
- Optimized Gate Charge to Minimize Driver Losses
- RoHS Compliant, Halogen Free and Lead Free

3. Applications

- Load Switch
- General PWM Applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit		
Absolute	Absolute maximum rating								
V _{DS}	drain-source voltage				30		V		
V _{GS}	gate-source voltage				±12		V		
I _D	continuous drain current	V _{GS} = 4.5 V; T _a = 25 °C			2.7		Α		
P _{tot}	power dissipation	T _a = 25 °C			1.4		W		
T _j	junction temperature			-55 to 150		°C			
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit		
Static cha	aracteristics						•		
R _{DS(on)}	drain-source on-state	$V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A}$		-	100	120	mΩ		
	resistance	V _{GS} = 2.5 V, I _D = 3 A		-	124	145	mΩ		
Dynamic (Dynamic characteristics								
$Q_{G(tot)}$	total gate charge	$I_D = 3 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V}$		-	2.7	-	nC		

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	2	D
2	S	source		
3	D	drain	1 2	sym300 S

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WMS30N1200SK	SOT23	WMS30N1200SKX	Reel	3000	SOT23L	22-Aug-2022

7. Marking

Table 4. Marking codes

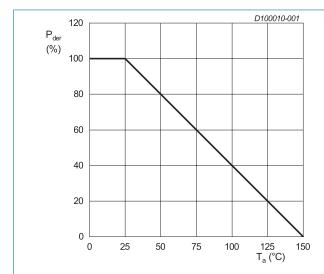
Type number	Marking codes
WMS30N1200SK	AJ

8. Limiting values

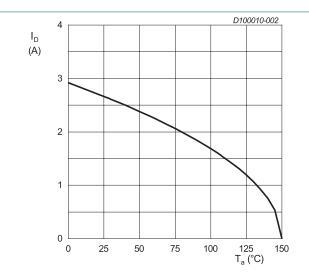
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			30	V
V_{GS}	gate-source voltage			±12	V
I _D	continuous drain current	V _{GS} = 4.5 V; T _a = 25 °C		2.7	Α
		V _{GS} = 4.5 V; T _a = 70 °C		2.1	Α
I _{DM}	pulsed drain current	t _p = 10 μs; T _a = 25 °C		11	Α
P _{tot}	power dissipation	T _a = 25 °C		1.4	W
T _{stg}	storage temperature			-55 to 150	°C
T _j	junction temperature			-55 to 150	°C



P_{der} = (P_{tot} / P_{tot(25 °C)}) x 100% Fig. 1. Normalized total power dissipation as a function of ambient temperature



V_{GS} = 4.5 V
Fig. 2. Continuous Drain Current as a function of ambient temperature

9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbo	I Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-a)}}$	thermal resistance from junction to	t ≤ 10s	[1]	-	72	90	K/W
	ambient	in free air	[1]	-	95	120	K/W

[1] Surface mount on FR4 board of 1 inch2, 1 oz copper.

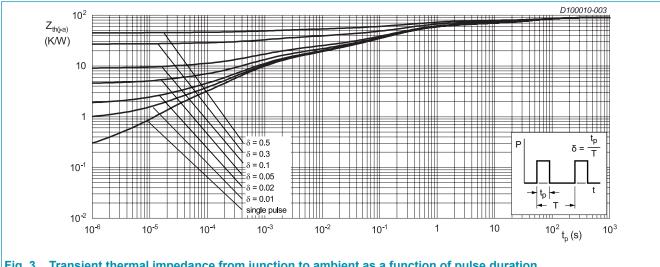


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration

10. Characteristics

Table 7. Characteristics

T_i = 25 °C unless otherwise noted

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V$		30	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	$I_D = 250 \ \mu A; \ V_{DS} = V_{GS}$		0.6	0.9	1.5	V
I _{DSS}	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}$		-	-	1	μA
		$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C}$		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 12 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
R _{DS(on)}	drain-source on-state	$V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}$		-	100	120	mΩ
	resistance	V _{GS} = 2.5 V; I _D = 3 A		-	124	145	mΩ
R_G	gate resistance	f = 1 MHz		-	2.8	-	Ω
Dynamic	characteristics						
Q _{G(tot)}	total gate charge	$I_D = 3 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V}$		-	2.7	-	nC
Q _{GS}	gate-source charge			-	0.9	-	nC
Q_{GD}	gate-drain charge			-	0.3	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz		-	128	-	pF
C _{oss}	output capacitance			-	23	-	pF
C _{rss}	reverse transfer capacitance			-	13	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V}; R_G = 6 \Omega;$		-	12	-	ns
t _r	rise time	$I_D = 3 A$		-	5.8	-	ns
$t_{\text{d(off)}}$	turn-off delay time			-	25	-	ns
t _f	fall time			-	4.0	-	ns
Source-d	rain diode		'				
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 1 A		-	0.80	1	V
		V _{GS} = 0 V; I _S = 1 A; T _j = 125 °C		-	0.67	-	V
I _S	body-diode continuous current	T _a = 25 °C		-	-	2	А
t _{rr}	reverse recovery time	$V_{GS} = 0 \text{ V; } I_S = 3 \text{ A; } di/dt = 100 \text{ A/}\mu\text{s}$		-	9.9	-	ns
Q _{rr}	reverse recovered charge			-	2.0	-	nC
I _{rrm}	reverse recovery current			-	0.3	-	Α

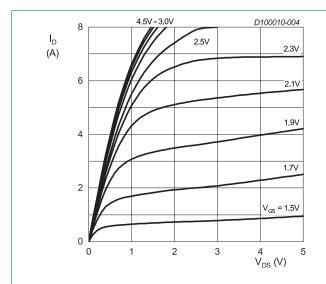
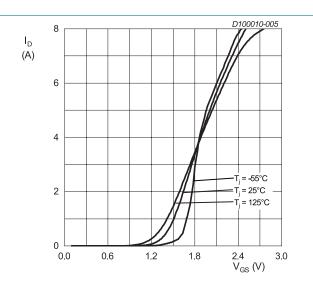
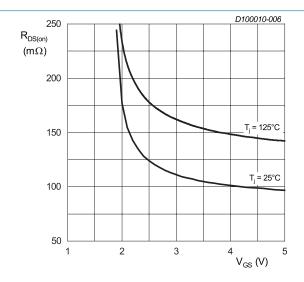


Fig. 4. Drain current as a function of drain-source voltage; typical values



V_{DS} = 5 V

Fig. 5. Drain current as a function of gate-source voltage; typical values



V_{GS} = 4.5 V; I_D = 3 A

Fig. 6. Drain-source on-state resistance as a function of gate-source voltage; typical values

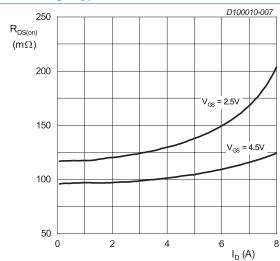
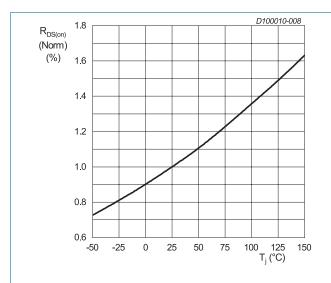
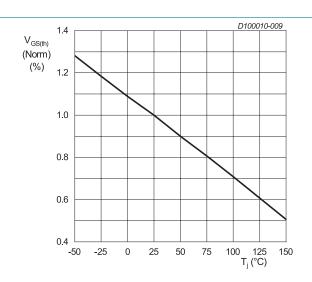


Fig. 7. Drain-source on-state resistance as a function of drain current; typical values



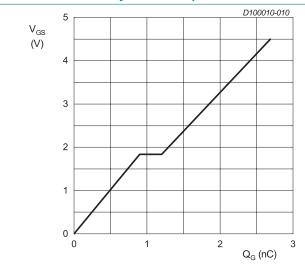
 $V_{GS} = 4.5 \text{ V}; I_D = 3 \text{ A}$

Fig. 8. Normalized drain-source on-state resistance as a function of junction temperature

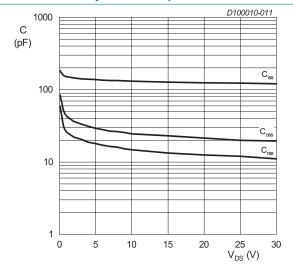


 V_{DS} = V_{GS} ; I_D = 250 μA

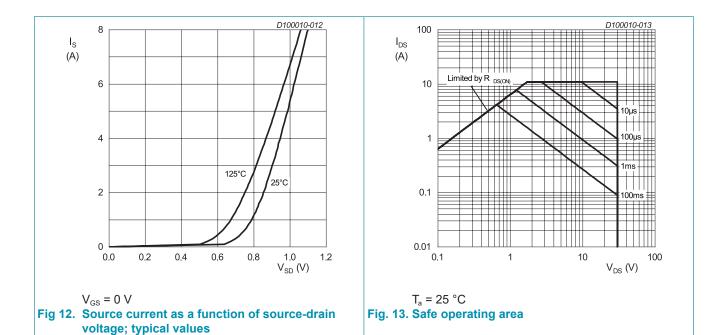
Normalized gate-source threshold voltage as a Fig. 9. function of junction temperature



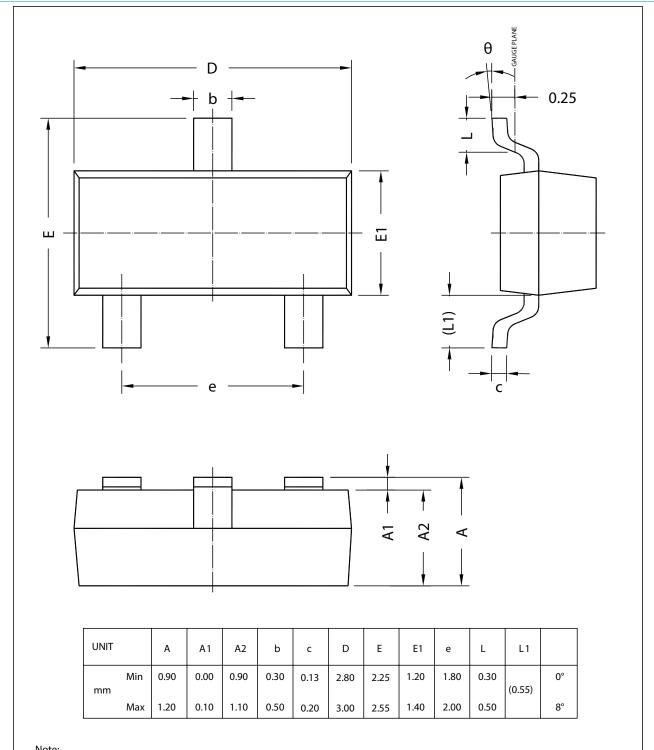
 $I_D = 3 A; V_{DS} = 15 V$ Fig. 10. Gate-source voltage as a function of gate charge; typical values



 V_{GS} = 0 V; f = 1 MHz Fig 11. Capacitances as a function of drain-source voltage; typical values



11. Package outline



Note:

1. All dimensions don't include mold flash and metal protrusion.

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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